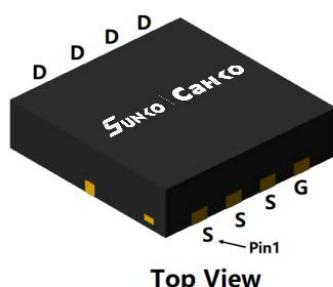
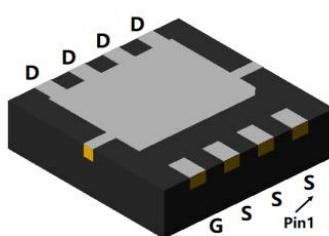
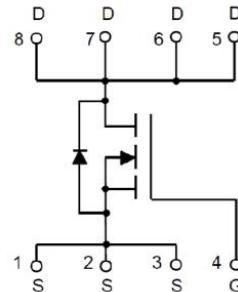


N-Channel Enhancement Mode Field Effect Transistor

Top View



Bottom View

DFN3333-8L**Product Summary**

- V_{DS} 30V
- I_D 50A
- $R_{DS(ON)}$ (at $V_{GS} = 10V$) < 6.0mohm
- $R_{DS(ON)}$ (at $V_{GS} = 4.5V$) < 8.0mohm
- 100% EAS Tested

General Description

- Trench Power LV MOSFET technology
- Excellent package for heat dissipation
- High density cell design for low $R_{DS(ON)}$
- Moisture Sensitivity Level 3
- Epoxy Meets UL 94 V-0 Flammability Rating
- Halogen Free

Applications

- High current load applications
- Load switching
- Hard switched and high frequency circuits
- Uninterruptible power supply

■ Absolute Maximum Ratings ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Limit	Unit
Drain-source Voltage		V_{DS}	30	V
Gate-source Voltage		V_{GS}	± 20	V
Drain Current	$T_c=25^\circ\text{C}$	I_D	50	A
	$T_c=100^\circ\text{C}$		32	
Pulsed Drain Current ^A		I_{DM}	190	A
Total Power Dissipation	$T_c=25^\circ\text{C}$	P_D	25	W
	$T_c=100^\circ\text{C}$		10	
Single Pulse Avalanche Energy ^B		E_{AS}	112.5	mJ
Thermal Resistance Junction-to-Case ^C		$R_{\theta JC}$	5	$^\circ\text{C} / \text{W}$
Junction and Storage Temperature Range		T_J, T_{STG}	-55~+150	$^\circ\text{C}$

■ Ordering Information (Example)

PREFERRED P/N	PACKING CODE	Marking	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
SCQ50N03B	F1	Q50N03B	5000	10000	100000	13" reel

■ Electrical Characteristics ($T_J=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Static Parameter						
Drain-Source Breakdown Voltage	BV_{DSS}	$V_{\text{GS}}=0\text{V}, I_{\text{D}}=250\mu\text{A}$	30			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{\text{DS}}=30\text{V}, V_{\text{GS}}=0\text{V}$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{\text{GS}}= \pm 20\text{V}, V_{\text{DS}}=0\text{V}$			± 100	nA
Gate Threshold Voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}}=V_{\text{GS}}, I_{\text{D}}=250\mu\text{A}$	1.0	1.5	2.5	V
Static Drain-Source On-Resistance	$R_{\text{DS}(\text{ON})}$	$V_{\text{GS}}= 10\text{V}, I_{\text{D}}=15\text{A}$		3.9	6.0	$\text{m}\Omega$
		$V_{\text{GS}}= 4.5\text{V}, I_{\text{D}}=15\text{A}$		6.0	8.0	
Diode Forward Voltage	V_{SD}	$I_{\text{S}}=20\text{A}, V_{\text{GS}}=0\text{V}$			1.2	V
Maximum Body-Diode Continuous Current	I_{S}				50	A
Dynamic Parameters						
Input Capacitance	C_{iss}	$V_{\text{DS}}=15\text{V}, V_{\text{GS}}=0\text{V}, f=1\text{MHz}$		2191		pF
Output Capacitance	C_{oss}			300		
Reverse Transfer Capacitance	C_{rss}			247		
Switching Parameters						
Total Gate Charge	Q_g	$V_{\text{GS}}=10\text{V}, V_{\text{DS}}=15\text{V}, I_{\text{D}}=20\text{A}$		46.3		nC
Gate-Source Charge	Q_{gs}			8.8		
Gate-Drain Charge	Q_{gd}			9.2		
Reverse Recovery Charge	Q_{rr}	$I_{\text{F}}=20\text{A}, \frac{dI}{dt}=500\text{A/us}$		1.6		ns
Reverse Recovery Time	t_{rr}			11		
Turn-on Delay Time	$t_{\text{D(on)}}$			11		
Turn-on Rise Time	t_r	$V_{\text{GS}}=10\text{V}, V_{\text{DD}}=15\text{V}, R_{\text{L}}=0.75\Omega, R_{\text{GEN}}=3\Omega$		80		ns
Turn-off Delay Time	$t_{\text{D(off)}}$			39		
Turn-off fall Time	t_f			92		

A. Pulse Test: Pulse Width $\leq 300\text{us}$, Duty cycle $\leq 2\%$.B. $T_J=25^\circ\text{C}$, $V_{\text{DD}}=25\text{V}$, $V_{\text{G}}=10\text{V}$, $L=1\text{mH}$, $I_{\text{AS}}=15\text{A}$ C. R_{\thetaJA} is the sum of the junction-to-Case and Case-to-ambient thermal resistance, where the case thermal reference is defined as the solder mounting surface of the drain pins. R_{\thetaJC} is guaranteed by design, while R_{\thetaJA} is determined by the board design. The maximum rating presented here is based on mounting on a 1 in 2 pad of 2oz copper.

■ Typical Performance Characteristics

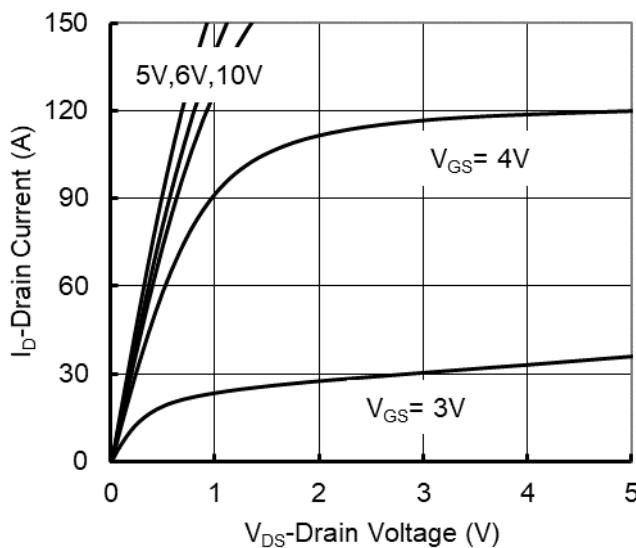


Figure 1. Output Characteristics

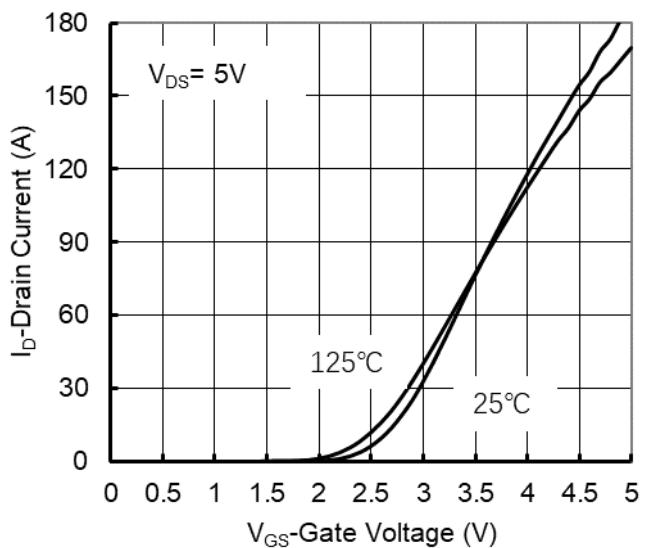


Figure 2. Transfer Characteristics

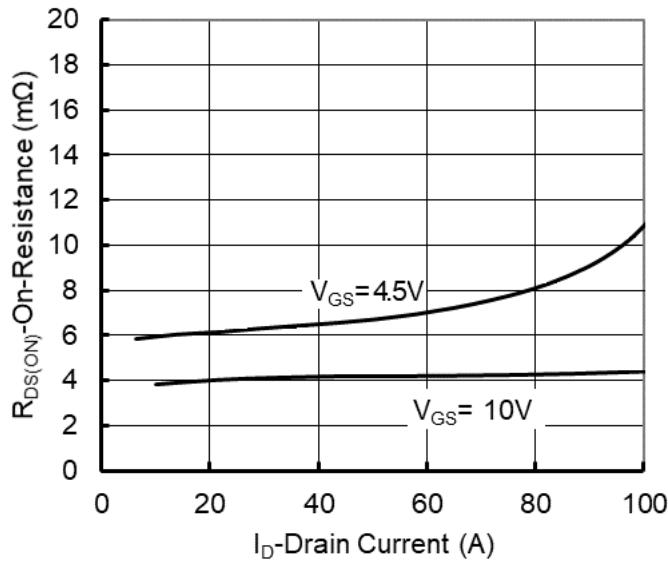


Figure 3. On-Resistance vs. Drain Current and Gate Voltage

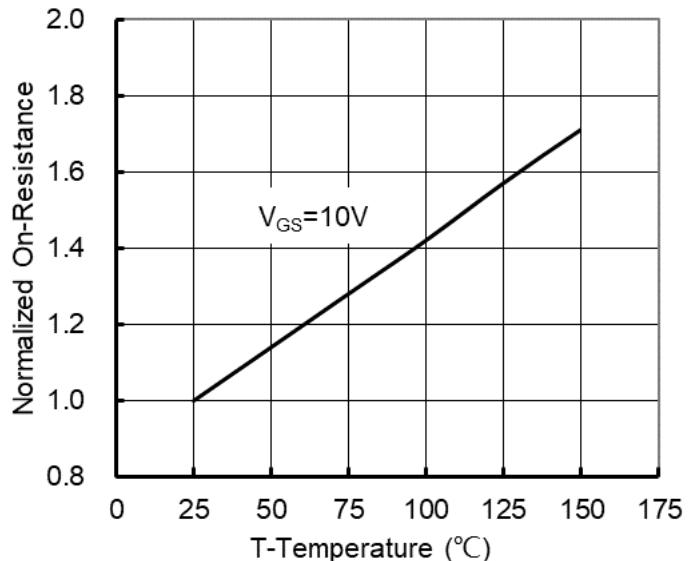


Figure 4. On-Resistance vs. Junction Temperature

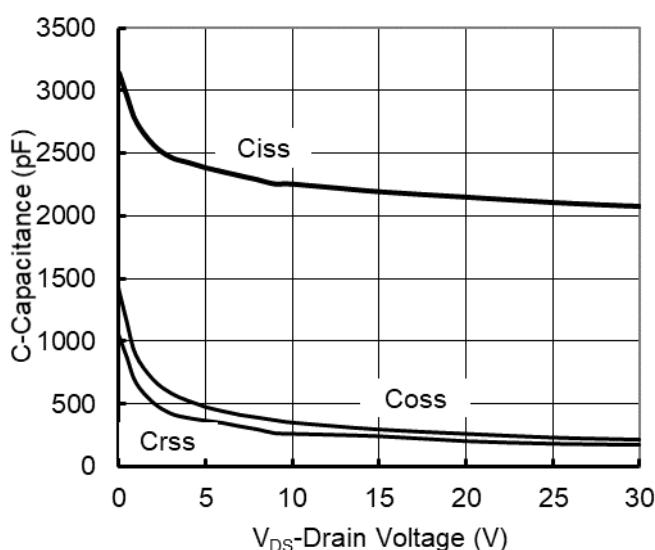


Figure 5. Capacitance Characteristics

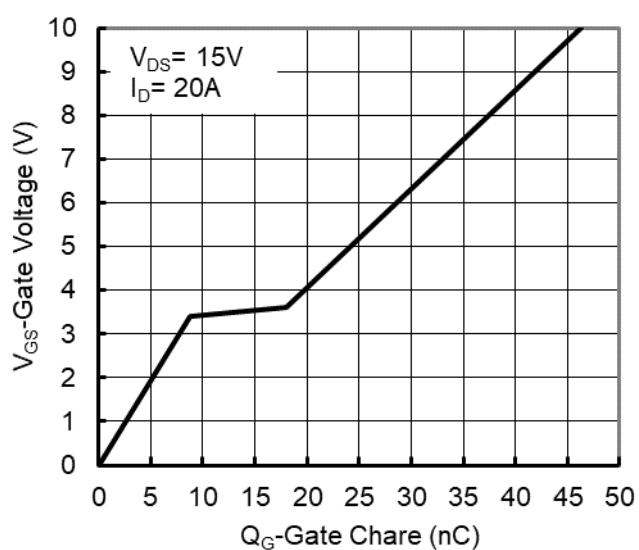


Figure 6. Gate Charge

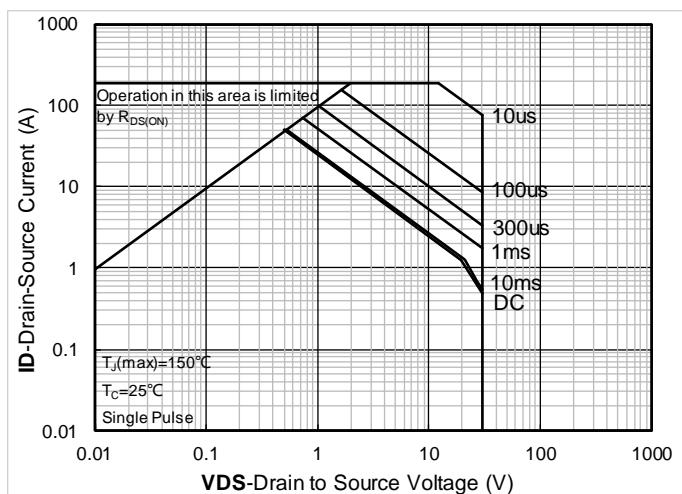


Figure 7. Safe Operation Area

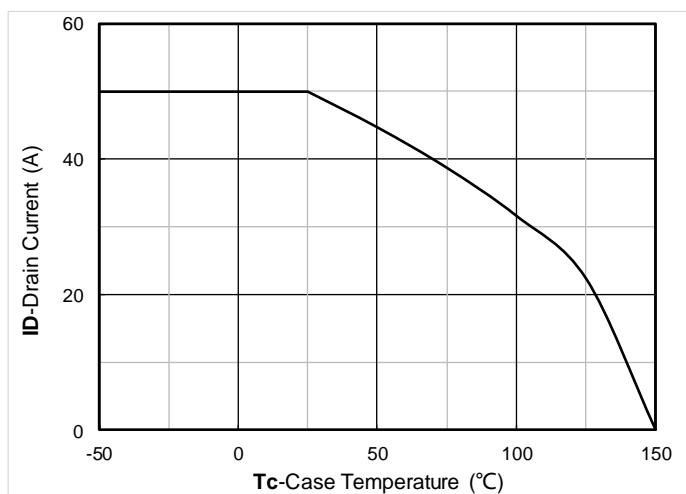


Figure 8. Maximum Continuous Drain Current vs Case Temperature

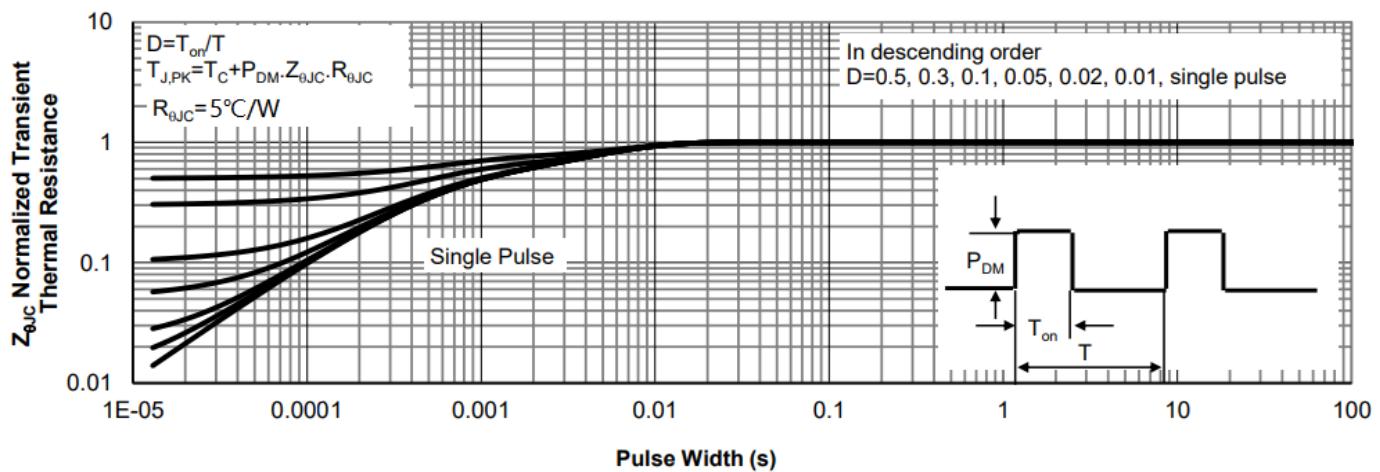
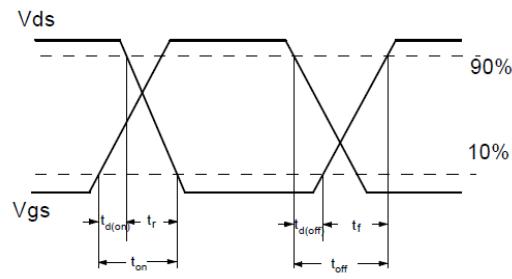
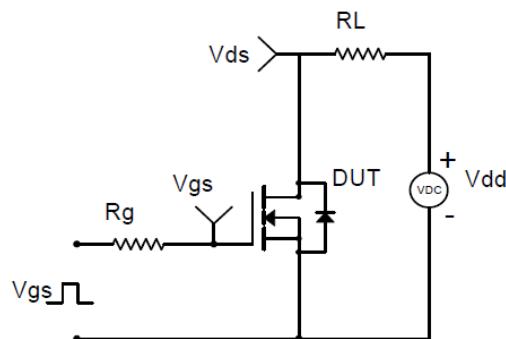
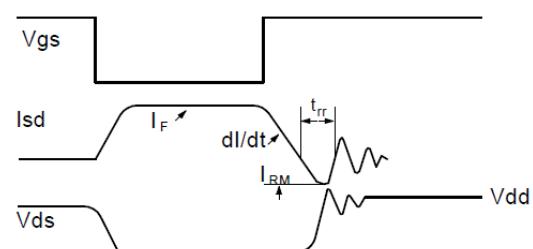
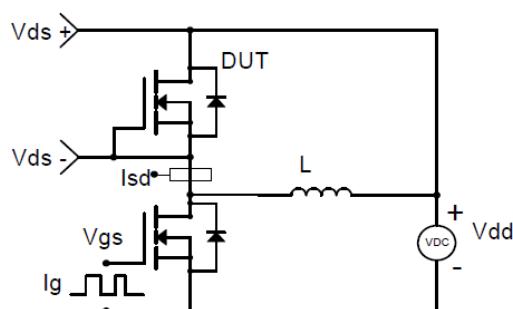


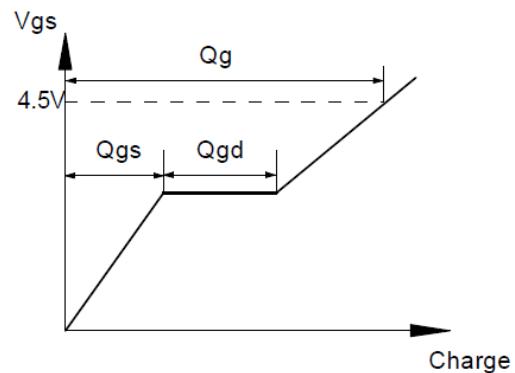
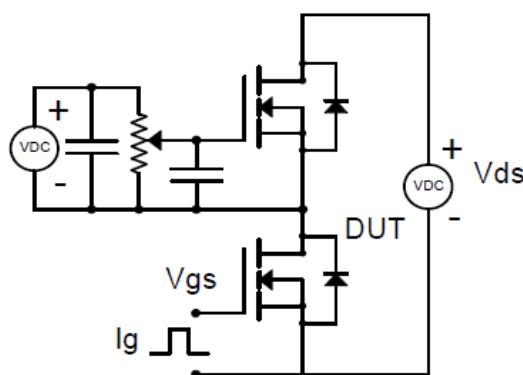
Figure 9. Normalized Maximum Transient Thermal Impedance



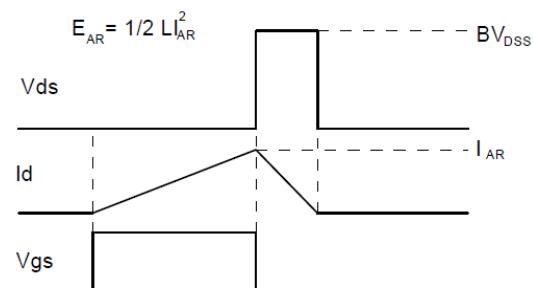
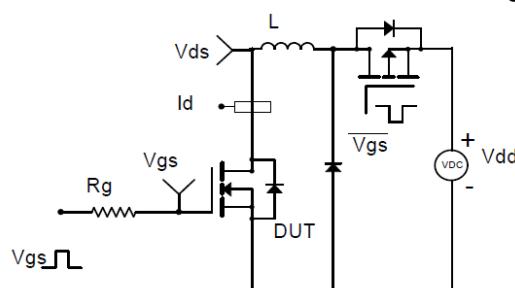
Resistive Switching Test Circuit & Waveforms



Diode Recovery Test Circuit & Waveforms

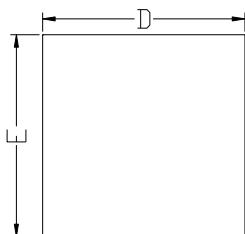


Gate Charge Test Circuit & Waveform

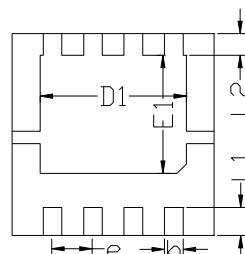


Unclamped Inductive Switching (UIS) Test Circuit & Waveforms

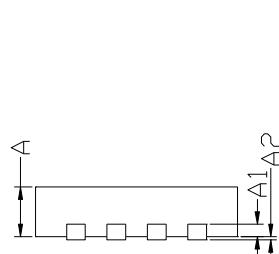
■ DFN3333-8L Package information



Top View
正面视图



Bottom View
背面视图

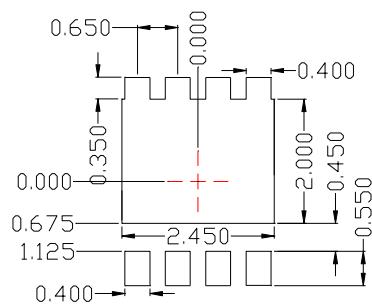


Side View
侧面视图

SYMBOL	MILLIMETER		
	MIN	NOM	MAX
D	3.15	3.25	3.35
E	3.15	3.25	3.35
A	0.70	0.80	0.90
A1	0.20	BSC	
A2			0.10
D1	2.20	2.35	2.50
E1	1.80	1.90	2.00
L1	0.35	0.45	0.55
L2	0.35	BSC	
b	0.20	0.30	0.40
e	0.65	BSC	

Note:

1. Controlling dimension: in millimeters.
2. General tolerance: +/- 0.10mm.
3. The pad layout is for reference purposes only.



Suggested Solder Pad Layout
Top View

Disclaimer

The information presented in this document is for reference only. Shanghai Sunco Electronics Co., Ltd reserves the right to make changes without notice for the specification of the products displayed herein to improve reliability, function or design or otherwise.

The product listed herein is designed to be used with ordinary electronic equipment or devices, and not designed to be used with equipment or devices which require high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices). Russiansunco or anyone on its behalf, assumes no responsibility or liability for any damages resulting from such improper use of sale.

This publication supersedes & replaces all information previously supplied. For additional information, please visit our website <http://www.russiansunco.co> or consult your nearest Russiansunco's sales office for further assistance.